P Kangra

Department: ECE Subject: PoEC

Course: Diploma Duration: 03 Years

Syllabus Planned

Total Periods: 56(T) + 42(P)

SYLLABUS PLANNED

Sr. No.	Period No.	Topic Covered	Instruction Reference	Additional Study recommended	Remarks
1	1-10	Analog Modulation: Concept of frequency translation, Amplitude Modulation: Description of full AM, DSBSC, SSB and VSB in time and frequency domains, methods of generation & demodulation, descriptions of FM signal in time and frequency domains.	Commiscotion		
2	11-23	Pulse Analog Modulation: Ideal sampling, Sampling theorem, aliasing, interpolation, natural and flat top sampling in time and frequency domains.	Communication Systems: Analog & Digital by RP Singh & SD Sapre		
3	24-33	PCM & Delta Modulation Systems: Uniform and Non-uniform quantization. PCM and delta modulation, Signal to quantization noise ratio in PCM and delta modulation.	SD Sapre And Analog		
4	34-46	Digital Modulation: Baseband transmission: Line coding (RZ, NRZ), inter symbol interference (ISI), pulse shaping. Nyquist criterion for distortion free base band transmission, raised cosine spectrum. Pass band transmission: Geometric interpretation of signals, orthogonalization.	P. Chakrabar	a a	
5	47-56	Spread-Spectrum Modulation: Introduction, Pseudo-Noise sequences, direct sequence spread spectrum (DSSS) with coheren BPSK, processing gain, probability of error frequency-hop spread spectrum (FHSS Application of spread spectrum; CDMA.	•		

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GP Kangra	Department: ECE Subject: Electronic Devices & Circuits
	Course: Diploma Duration: 03 Years
Syllabus Planned	Total Periods: 56(T) + 42(P)

SYLLABUS PLANNED

Sr. No.	Period No.	Topic Covered	Instruction Reference	Additional Study recommended	Remarks
1	1-11	Semiconductor and Diodes: Definition, Extrinsic/Intrinsic, N-type & P-type. PN Junction Diode – Forward and Reverse Bias Characteristics. Zener Diode – Principle, characteristics, construction, and working. Diode Rectifiers – Half Wave and Full Wave. Filters – C, LC, and PI Filters.			
2	12-23	Bipolar Junction Transistor (BJT): NPN and PNP Transistor – Operation and characteristics. Common Base Configuration – characteristics and working. Common Emitter Configuration – characteristics and working. Common Collector Configuration – characteristics and working. High frequency model of BJT. Classification of amplifiers, negative feedback.			
3	24-34	Field Effect Transistors: FET. – Working Principle, Classification. MOSFET Small Signal model. N-Channel/ P- Channel MOSFETs – characteristics, enhancement, and depletion mode, MOS- FET as a Switch. Common Source Amplifiers. Uni- Junction Transistor – equivalent circuit and operation.			
4	35-46	SCR DIAC & TRIAC: SCR - Construction, operation, working, characteristics. DIAC - Construction, operation, working, characteristics. TRIAC - Construction, operation, working, characteristics. SCR and MOSFET as a Switch, DIAC as bidirectional switch. Comparison of SCR, DIAC, TRIAC, MOSFET.			
5	47-56	Amplifiers and Oscillators: Feedback Amplifiers – Properties of negative Feedback, impact of feedback on different parameters. Basic Feedback Amplifier			

Topologies: Voltage Series, Voltage Shunt. Current Series, Current Shunt. Oscillator – Basic Principles, Crystal Oscillator, Non-linear/ Pulse	
Oscillator .	

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Extra Topics to be covered beyond the scope of the syllabus (as required by industry/ as recommended by Teacher which he/ she find as necessary)

Sr. No.	Period No.	Topic Covered	Instruction Reference	Additional Study recommended	Remarks

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G	P	Departmen	SYLLABUS COVERAGE (THEORY) t:Subject		-	
K	angra		Duration		-	
SYI	LABUS VERAGE					
Sr	Period	Topic	s Theory	Instruction	Additional	Remarks
No	Nos.	Topic	Details	Reference	Study Recommended	
1	1 -	1. Number				
	10	Systems &	Introduction to different number systems – Binary,			
		Boolean	Octal decimal Hexadecimal, Conversion from one			
		Algebra:	number system to another. Boolean variables – Rules			
			and laws of Boolean algebra. De-Morgan's Theorem. Karnaugh Maps and their use for simplification of			
			Boolean expressions		/	
2	11-19		THE OF NOT MAND NOR YOR			
		2. Logic Gates:	Logic Gates – AND, OR, NOT, NAND, NOR, XOR, XNOR: Symbolic representation and truth table.			
		Gates:	Implementation of Boolean expressions and Logic			
		12.0	Functions using gates. Simplification of expressions.			
		2	Arithmetic Circuits – Addition, Subtraction, 1's &2's			
3	20.20	3. Combinatio	Complement, Half Adder, Full Adder, Half			
3	20-30	nal Logic	Subtractor, Full Subtractor, Parallel and Series			
		Circuits:	Adders Encoder, Decoder. Multiplexer – 2 to 1 MUX, 4 to 1 MUX, 8 to 1 MUX and their			
		370	Applications, Demultiplexer – 1-2 DEMUX, 1-4			
		*	DEMUX, 1-8 DEMUX.			
4	31-46	4. Sequential	Flip Flops – SR, JK, T, D, JK-MS, Triggering.			
		Logic	Counters – 4bit Up – Down Counters,			
		Circuits:	Asynchronous/ Ripple Counter, Decade Counter- Mod 3, Mod 7 Counter, Johnson Counter, Ring			
			Counter. Registers – 4bit Shift Register: Serial In			
			Serial Out, Serial In Parallel Out, Parallel In Serial			
			Out, Parallel In Parallel Out.			
5.	47-56	5. Memory	Classification of Memories – RAM Organization,			
٥.	71-30	Devices:	Address Lines and Memory Size, Static RAM,			
			Bipolar RAM, Cell Dynamic RAM, D RAM, DDR			
			RAM. Rad only memory – ROM organization, Expanding			
			memory, PROM, EPROM, EEPROM, Flash			
			memory. Data Converters – Digital to Analog			
			converters, Analog to Digital Converters			
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G P Kangra

Practical Planning & Coverage Status

Department: Electronics and communication Egg. Laboratory: Digital Electronics Lab

Course: Diploma

Subject: Digital Electronics Lab

Sr.	Details of Practical	Availal	bility of	Likely	Actual	Responsibility	HOD Sign.	Remarks
No.		Equipment Set up	STD Ref. Write up	Turn/Date	Date		Sigit.	
1.	1. To verify the truth tables for all logic fates - NOT OR AND NAND NOR XOR XNOR using CMOS Logic gates and TTL Logic Gates.	Standard Trainer kits						
2.	2. Implement and realize Boolean Expressions with Logic Gates.							
3.	3. Implement Half Adder, Full Adder, Half Subtractor, Full subtractor using ICs.							
4.	4. Implement parallel and serial full-adder using ICs.							
5.	5. Design and development of Multiplexer and De-multiplexer using multiplexer ICs.							
6.	6. Verification of the function of SR,D, JK and T Flip Flops.							

7.	7. Design controlled shift registers.			
8	8. Construct a Single digit Decade Counter (0-9) with 7 segment display			
9	9. To design a programmable Up-Down Counter with a 7-segment display.			
10	10. Study of different memory ICs.			
11	11. Study Digital- to – Analog and Analog to Digital Converters.			
12	12. Simulate in Software (such as PSpice) an Analog to Digital Converter			



PLANNED SYLLABUS COVERAGE (Theory)

GP		Department: E	MEASURI	EMENT	NIS AND		
Kangra		Course : Diplo	oma Dura	tion: 3 Yrs.			
	LABUS ERAGE	Total Period: Theory: 56 Practical: 28					
Sr. No.	Period Nos	Topic	Details	Instruction Reference	Additional Study Recommended	Remarks	
1.	1 TO 8	Basics of Measurements and Bridges	 1.1 Accuracy, precision, and Resolution. 1.2 Types of Errors 1.3 DC Bridges - Wheatstone Bridge. Kelvin Double Bridge. 1.4 AC Bridges - Maxwell's Bridge Hay's Bridge, Anderson Bridge, De-Sauty's Bridge. 	Electronics Measurement and Instrumentation by AKSawhney, Dhanpat Rai and Sons, New Delhi Electronics Measurement and Instrumentation by Oliver, Tata McGraw Hill Education Pvt Ltd, New Delhi	Electronics Instrumentatio n by Cooper, Prentice Hall of India, New Delhi		
2.	9 TO 17	Potentiometer	2.1 Basic DC slide wire Potentiometer. 2.2 Crompton's DC Potentiometer 2.3 Applications of DC Potentiometer. 2.4 AC Potentiometers 2.5 Applications of AC Potentiometers.	Electronics Measurement and Instrumentation by AK Sawhney, Dhanpat Rai and Sons, New Delhi Electronics Measurement and Instrumentation by Oliver, Tata McGraw Hill Education Pvt Ltd, New Delhi	Electronics Instrumentatio n by Cooper, Prentice Hall of India, New Delhi		

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	3.	18 26	то	Measuring Instruments:	3.1 Permanent Magnet Moving Coil Instruments (PMMC). 3.2 Moving Iron type Instruments (MI). 3.3 Electro Dynamo Type Instruments. 3.4 Single Phase Energy Meter.	Electronics Measurement and Instrumentation by AK Sawhney, Dhanpat Rai and Sons, New Delhi Electronics Measurement and Instrumentation by Oliver, Tata McGraw Hill Education Pvt Ltd, New Delhi	n by Cooper, Prentice Hall of India, New Delhi	
2	4.	28 34	ТО	Electronic Instruments:	 4.1Electronic Voltmeter and Digital Voltmeter 4.2Electronic Multimeters. Q – Meter. 4.3Vector Impedance Meter. 	Electronics Measurement and Instrumentation by AK Sawhney, Dhanpat Rai And Sons, New Delhi Electronics Measurement and Instrumentation by Oliver, Tata McGraw Hill Education Pvt Ltd, New Delhi	Electronics Instrumentatio n by Cooper, Prentice Hall of India, New Delhi	
5	5.	35 46	то	Oscilloscopes	5.1 Cathode ray tube: construction, operation, screens, graticules. Vertical deflection system, Horizontal deflection system, Delay line, Measurement of frequency, time delay, phase angle and modulation index (trapezoidal method). 5.2 Oscilloscope probe: Structure of 1:1 and 10:1 probe. Multiple Trace CRO.	Electronics Measurement and Instrumentation by AK Sawhney, Dhanpat Rai and Sons, New Delhi Electronics Measurement and Instrumentation by Oliver, Tata McGraw Hill Education Pvt Ltd, New Delhi	Electronics Instrumentatio n by Cooper, Prentice Hall of India, New Delhi	

G P Kangra Practical Planning & Coverage Status

Department: Electronics and Communication Engineering

Course: Diploma

Laboratory: EIM LAB
Subject: ELECTRONIC INSTRUMENTS AND
MEASUREMENT

Remarks

		Availability of		Likely	Actual	Responsibility	Sign.	
Sr.N	Details of Practical	Equipment Set up	STD Ref. Write up	Turn/Date	Date			
1	Measure unknown inductance using following bridges (a) Anderson Bridge (b)	bridges Anderson Bridge	Trainer Kit Manual	G ₁ :	G ₁ :			
	Maxwell Bridge	Maxwell Bridge	iviandar	G ₂ :	G ₂ :			
2	Measure Low resistance by Kelvin's	Kelvin's	do	G ₁ :	G ₁ :			
	Double Bridge	Double Bridge		G ₂ :	G ₂ :			
3	Calibrate an ammeter using DC slide wire	DC slide		G ₁ :	G ₁ :			
	potentiometer	wire potentiome ter	do	G ₂ :	G ₂ :			
1	Calibrate a voltmeter using Crompton potentiometer	Crompton	do	G ₁ :	G ₁ :			
		ter .		G ₂ :	G ₂ :			
5	Measure low resistance by Crompton potentiometer	Crompton	do	G ₁ : G ₂ :	G ₁ : G ₂ :			
		ter .						
6	Calibrate a single-phase energy meter by phantom loading	single- phase energy meter	do	G ₁ : G ₂ :	G ₁ : G ₂ :			

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7	Study the working of Q-meter and measure Q of coils	Q-meter	Trainer Kit Manual	G ₁ : G ₂ :	G ₁ : G ₂ :		
8	Study working and applications of (i) C.R.O. (ii) Digital Storage C.R.O. & (iii) C.R.O. Probes	Digital Storage C.R.O	do	G ₁ : G ₂ :	G ₁ : G ₂ :		
9.	Measurement of displacement with the help of LVDT.	LVDT.	do	G ₁ : G ₂ :	G ₁ : G ₂ :		
10.	Draw the characteristics of the following temperature transducers (a) RTD (Pt-100) (b) Thermistor	temperature transducers (a) RTD (Pt-100) (b) Thermistor	do	G ₁ : G ₂ :	G ₁ : G ₂ :		
11.	Measurement of strain/force with the help of strain gauge load cell	strain gauge load cell	do	G ₁ : G ₂ :	G ₁ : G ₂ :		

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GP Kangra	Department: ECE	Subject: ECN
	Course: Diploma	Duration: 03 Years
Syllabus Planned	Total Periods: 56(T)	Theory: 56

SYLLABUS PLANNED

S. N.	Period No.	Topic Covered	Instruction Reference	Additional Study recommen ded	Remark s
1	1-12	Basics of Network and Network Theorem: Node and Mesh Analysis, Superposition Theorem, Thevenin Theorem, Norton Theorem, Maximum Power transfer theorem, Reciprocity Theorem			
2	13-18	Two Port Network: Introduction of the Two Port Network and the various network parameters i.e., Open Circuit Impedance Parameters. Short Circuit Admittance Parameters. Transmission Parameters, Introduction of Hybrid Parameters.			
3	19-27	Graph Theory: Concept of Graph, Node Tree of network, and incidence matrix and Analysis of resistive network using cut-set and tie-set, Duality Theorem and their application in the electrical circuits.	Network & Systems D.	Netwok Theory by A.K.	
4	28-42	Time Domain and Frequency Domain Analysis: Solution of first and second order differential equations for Series and parallel R-L, R-C, R-L-C circuits. Initial and Final conditions in network elements. Forced and Free response, time constants. Steady State and Transient State Response. Analysis of electrical circuits using Laplace Transform for standard inputs (unit, Ramp, Step).	Roy Choudhury Wiley Eastern Ltd	Choudhary	
5	43-56	Trigonometric and exponential Fourier series: Discrete spectra and symmetry of waveform. Steady state response of a network to non-sinusoidal periodic inputs, power factor, effective values. Fourier transform and continuous spectra.			

Extra Topics to be covered beyond the scope of the syllabus (as required by industry/ as recommended by Teacher which he/ she find as necessary)

S. N.	Period No.	Topic Covered	Instruction Reference	Additiona 1 Study recomme nded	Rer
1 2	1-2 28-29	KVL, KCL, Network Basics. AC & DC source application in RL, RC, RLC circuits	Network & Systems D. Roy Choudhury Wiley Eastern Ltd	Introduction to Electrical Technology by BL Theraja & AK Theraja	

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